

Can thin-film silicon photovoltaics be used for solar energy?

The ability to engineer efficient silicon solar cells using a-Si:H layers was demonstrated in the early 1990s [113, 114]. Many research laboratories with expertise in thin-film silicon photovoltaics joined the effort in the past 15 years, following the decline of this technology for large-scale energy production.

Can silicon PV devices be made without rare materials?

Silicon PV devices can be made, even at the TW scale, without any rare or scarce materials, and substitution materials can be used for critical elements (for example, silver has been replaced with copper and indium with zinc and/or tin in SHJ cells).

Does thin-film silicon photovoltaics have a synergy?

Many research laboratories with expertise in thin-film silicon photovoltaics joined the effort in the past 15 years, following the decline of this technology for large-scale energy production. Their success suggests that strong synergies exist between the two fields [57, 79, 115, 116, 117, 118].

Why are solar cells based on n-type silicon more expensive?

In terms of processing, solar cells based on n-type silicon show a slightly higher complexity and higher manufacturing cost, as both phosphorus for the BSF and boron for the emitter (the region of the wafer showing opposite doping from the bulk) [48] have to be diffused, and because both front and rear metal layers require silver-based pastes.

Are methyl-silylated silica coatings suitable for concentrated solar applications?

Agustín-Sánchez, C., Machado, M., Zubillaga, O. & Tercjak, A. Hydrophobic and spectrally broadband antireflective methyl-silylated silica coatings with high performance stability for concentrated solar applications. *Sol. Energy Mater. Sol. Cells* 200, 109962 (2019).

Can a nanocrystalline silicon oxide interlayer be used for infrared light management?

Mazzarella, L. et al. Infrared light management using a nanocrystalline silicon oxide interlayer in monolithic perovskite/silicon heterojunction tandem solar cells with efficiency above 25%. *Adv. Energy Mater.* 9, 1803241 (2019). Al-Ashouri, A. et al. Monolithic perovskite/silicon tandem solar cell with >29% efficiency by enhanced hole extraction.

The evolution of photovoltaic cells is intrinsically linked to advancements in the materials from which they are fabricated. This review paper provides an in-depth analysis of ...

In this work, we propose and investigate on the light absorption enhancement of ultrathin c-Si cells via the design of front nanostructured silicon nitride (Si₃N₄) [32, 33] and ...

Yu, J. et al. Titanium nitride electron-conductive contact for silicon solar cells by radio frequency sputtering from a TiN target. ACS Appl. Mater. Interfaces 12, 26177-26183 ...

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We propose in this study to minimize the reflection at the air/glass interface by n-binary unit cell silicon nitride-metamaterial antireflective structures on glass. For this purpose, we apply the ...

Substantial advantages of plasma Si nitride, for the first time applied to silicon MIS inversion layer (MIS/IL) solar cells, are demonstrated: The highest positive interface charge densities ever ...

A significant portion of solar radiation (~35%) is reflected from the surface of the silicon solar cells, this leads to a solar cell efficiency reduction [1, 2]. Therefore, light trapping is ...

The most widely used antireflection coating is a silicon nitride film (about 75 nm thick with RI of about 2.10), deposited by plasma-enhanced chemical vapor deposition (PECVD). ... Wafer ...

Modules based on c-Si cells account for more than 90% of the photovoltaic capacity installed worldwide, which is why the analysis in this paper focusses on this cell type. ...

To passivate the surface of the emitters doped with phosphorus, homo-junction crystal silicon cells often use coatings of hydrogenated silicon nitride (SiN_x:H). For the purpose ...

Abstract. This work used plasma-enhanced chemical vapor deposition (PECVD) at low temperatures to deposit a silicon nitride layer on multicrystalline silicon (mc-Si), both ...

with a back silicon nitride (SiN_x) film in photovoltaic layer (PERC-II) are taking the leading role in the PV market, and the new tunnel oxide passivating contact (TOPCon) Si cells are emerging ...

Substantial advantages of plasma Si nitride, for the first time applied to silicon MIS inversion layer (MIS/IL) solar cells, are demonstrated: The highest positive interface ...

